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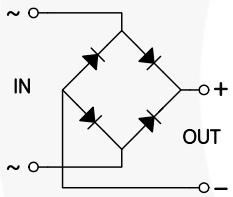
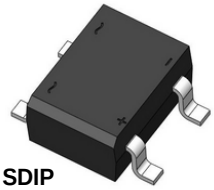
June 2015

DF005S1 - DF10S1
Bridge Rectifier

Features

- Maximum Surge Rating: I_{FSM} = 35 A
  I^2t = 5.1 A^2Sec
- Optimized V_F: Typical 0.95 V at 1 A, 25°C
- DF10S Socket Compatible
- Glass Passivated Junctions
- Lead Free Compliant to EU RoHS 2002/95/EU Directives
- Green Molding Compound: IEC61249
- Qualified with IR Reflow and Wave Soldering





Description

With the ever-pressing need to improve power supply efficiency, improve surge rating, improve reliability, and reduce size, the DFxS1 family sets a new standard in performance and cost saving.

The DFxS1 family balances performance against cost. The design offers a moderate surge rating of 35 A required to handle inrush surge and maintain good reliability, with fair price.

The DFxS1 achieves good performance in a SDIP surface mount form factor, reducing board space and volumetric requirements vs. competitive devices.

Ordering Information

Part Number	Top Mark	Package	Packing Method
DF005S1	DF005S1	SDIP 4L	Tape and Reel
DF01S1	DF01S1	SDIP 4L	Tape and Reel
DF02S1	DF02S1	SDIP 4L	Tape and Reel
DF04S1	DF04S1	SDIP 4L	Tape and Reel
DF06S1	DF06S1	SDIP 4L	Tape and Reel
DF08S1	DF08S1	SDIP 4L	Tape and Reel
DF10S1	DF10S1	SDIP 4L	Tape and Reel

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Value							Unit
		DF005S1	DF01S1	DF02S1	DF04S1	DF06S1	DF08S1	DF10S1	
V_{RRM}	Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
V_{RMS}	Maximum RMS Bridge Input Voltage	35	70	140	280	420	560	700	V
V_{DC}	Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
$I_{F(AV)}$	Maximum Average Forward Current T_A = 40°C	1.0							A
I_{FSM}	Peak Forward Surge Current 8.3 ms Single Half-Sine Wave Superimposed on Rated Load(JEDEC Method)	35							A
T_{STG}	Storage Temperature Range	-55 to +150							°C
T_J	Operating Junction Temperature Range	-55 to +150							°C

Thermal Characteristics(1)

Symbol	Parameter	Conditions	Max.	Unit
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	Single-Die Measurement (Maximum Land Pattern: 13 x 13 mm)	65	°C/W
		Multi-Die Measurement (Maximum Land Pattern: 13 x 13 mm)	50	
		Multi-Die Measurement (Minimum Land Pattern: 1.3 x 1.5 mm)	105	
Ψ_{JL}	Thermal Characterization Parameter, Junction to Lead	Single-Die Measurement (Maximum and Minimum Land Pattern)	27	°C/W

Note:

1. The thermal resistances ($R_{\theta JA}$ & Ψ_{JL}) are characterized with the device mounted on the following FR4 printed circuit boards, as shown in Figure 1 and Figure 2. PCB size: 76.2 x 114.3 mm.
   Heating effect from adjacent dice is considered and only two dices are powered at the same time.

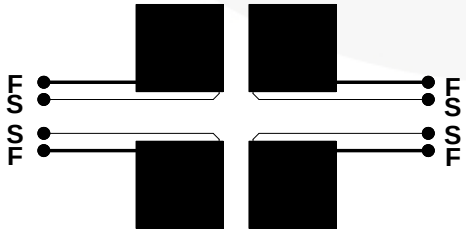


Figure 1. Maximum Pads of 2 oz Copper

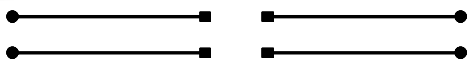


Figure 2. Minimum Pads of 2 oz Copper

Electrical Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_F	Forward Voltage Drop per Bridge Element	I_F = 1.0 A			1.1	V
I_R	DC Reverse Current at Rated DC Blocking Voltage	T_J = 25°C			3	μA
		T_J = 125°C			500	
I^2t	Rating for Fusing (t < 8.3 ms)				5.1	A^2S
C_J	Junction Capacitance	V_R = 4.0 V, f = 1.0 MHz		10		pF

Typical Performance Characteristics

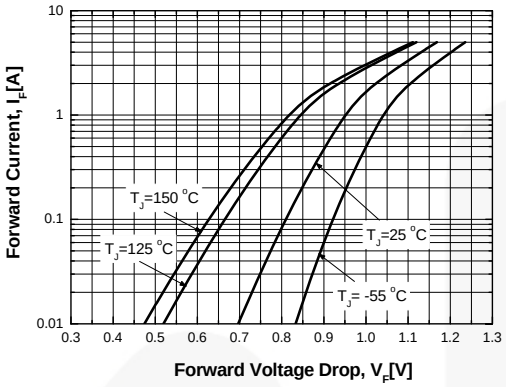


Figure 3. Typical Instantaneous Forward Characteristics

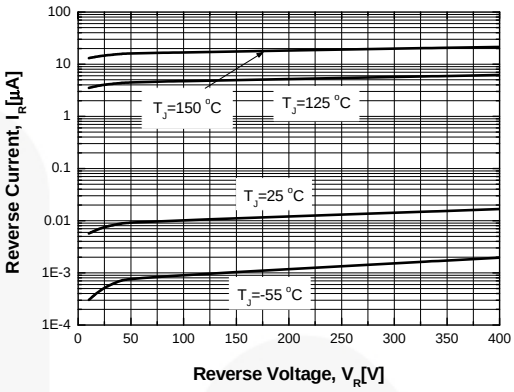


Figure 4. Typical Reverse Characteristics

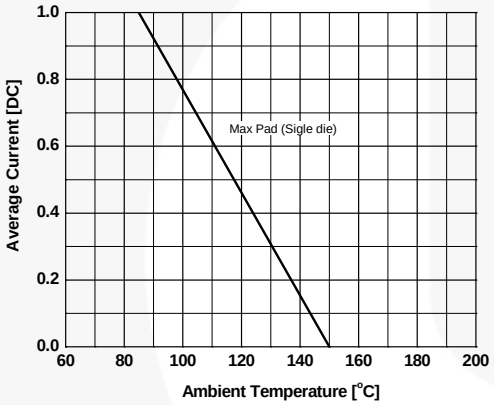


Figure 5. Maximum Average Current vs. Ambient Temperature

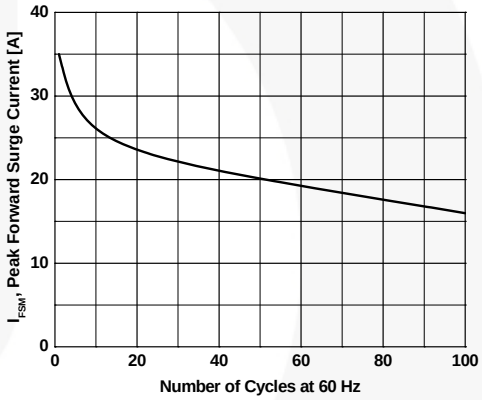


Figure 6. Peak Forward Surge Current vs. Number of Cycles at 60Hz

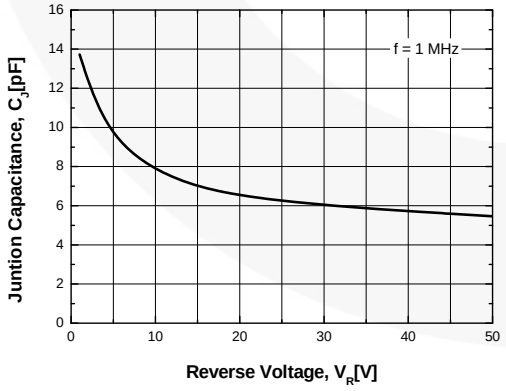
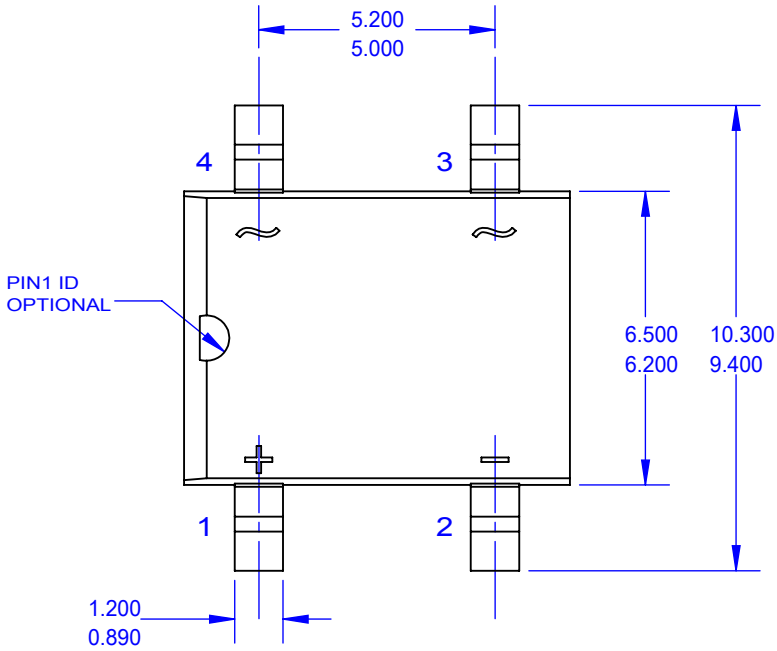
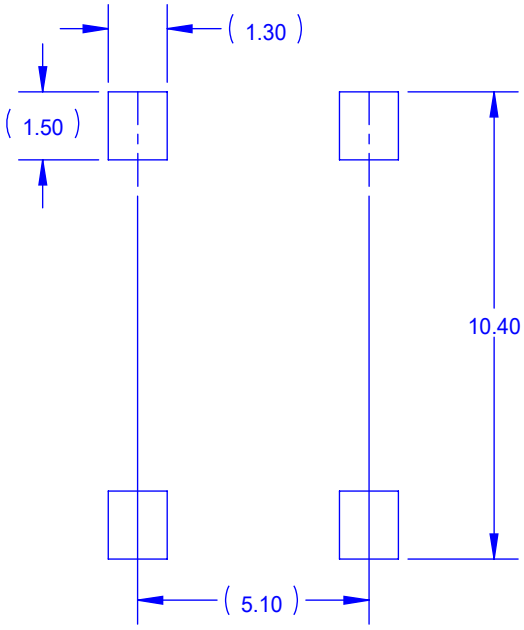


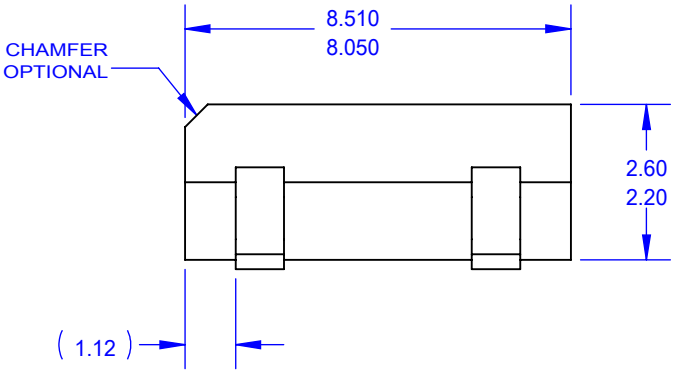
Figure 7. Typical Junction Capacitance



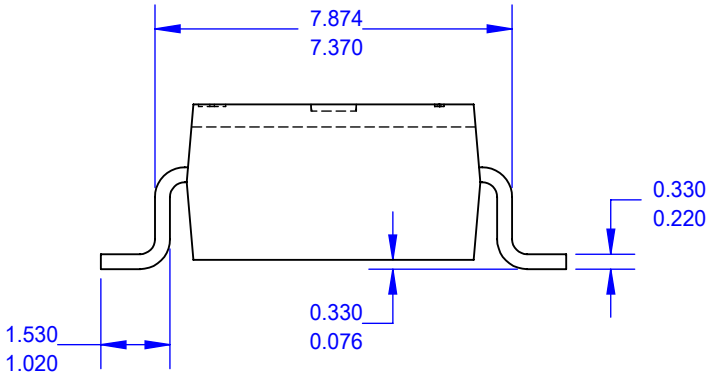
TOP VIEW



LAND PATTERN RECOMMENDATION



SIDE VIEW



END VIEW

NOTES:

A. THIS PACKAGE DOES NOT CONFORM TO ANY REFERENCE STANDARD.
B. ALL DIMENSIONS ARE IN MILLIMETERS.
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
G. DRAWING FILE NAME: MKT-SDIP04AREV5.

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